

**Features:**

- Isolated mounting base 3000V~
- Pressure contact technology with Increased power cycling capability
- Space and weight saving

**Typical Applications**

- AC/DC Motor drives
- Various rectifiers
- DC supply for PWM inverter

| $V_{DSM}, V_{RSM}$ | $V_{DRM}, V_{RRM}$ | Type & Outline   |
|--------------------|--------------------|------------------|
| 2100V              | 2000V              | MFx300-20-413F3D |
| 2300V              | 2200V              | MFx300-22-413F3D |
| 2600V              | 2500V              | MFx300-25-413F3D |

| SYMBOL                 | CHARACTERISTIC                             | TEST CONDITIONS  | $T_j$ (°C) | VALUE |      |      | UNIT                           |
|------------------------|--|--|------------|-------|------|------|--------------------------------|
|                        |  |  |            | Min   | Type | Max  |                                |
| $I_{T(AV)}$            | Mean on-state current                      | 180° half sine wave 50Hz<br>Single side cooled, $T_c=85^\circ\text{C}$ | 125        |       |      | 300  | A                              |
| $I_{T(RMS)}$           | RMS on-state current                       |  |            |       |      | 471  | A                              |
| $I_{DRM}$<br>$I_{RRM}$ | Repetitive peak current                    | at $V_{DRM}$<br>at $V_{RRM}$   | 125        |       |      | 40   | mA                             |
| $I_{TSM}$              | Surge on-state current                     | 10ms half sine wave  | 125        |       |      | 8    | kA                             |
| $I^2t$                 | $I^2t$ for fusing coordination             | $V_R=60\%V_{RRM}$  |            |       |      | 320  | $\text{A}^2\text{s}\cdot 10^3$ |
| $V_{TO}$               | Threshold voltage                          |  | 125        |       |      | 0.85 | V                              |
| $r_T$                  | On-state slope resistance                  |  |            |       |      | 0.65 | mΩ                             |
| $V_{TM}$               | Peak on-state voltage                      | $I_{TM}=900\text{A}$   | 25         |       |      | 1.99 | V                              |
| $dv/dt$                | Critical rate of rise of off-state voltage | $V_{DM}=67\%V_{DRM}$   | 125        |       |      | 800  | $\text{V}/\mu\text{s}$         |
| $di/dt$                | Critical rate of rise of on-state current  | Gate source 1.5A<br>$t_r \leq 0.5\mu\text{s}$ Repetitive               | 125        |       |      | 100  | $\text{A}/\mu\text{s}$         |
| $I_{GT}$               | Gate trigger current                       | $V_A=12\text{V}, I_A=1\text{A}$  | 25         | 30    |      | 200  | mA                             |
| $V_{GT}$               | Gate trigger voltage                       |  |            | 0.7   |      | 2.5  | V                              |
| $I_H$                  | Holding current                            |  |            | 10    |      | 200  | mA                             |
| $V_{GD}$               | Non-trigger gate voltage                   | $V_{DM}=67\%V_{DRM}$   | 125        | 0.2   |      |      | V                              |
| $R_{th(j-c)}$          | Thermal resistance<br>Junction to case     | Single side cooled per chip  |            |       |      | 0.10 | $^\circ\text{C}/\text{W}$      |
| $R_{th(c-h)}$          | Thermal resistance<br>case to heat sink    | Single side cooled per chip  |            |       |      | 0.04 | $^\circ\text{C}/\text{W}$      |
| $V_{ISO}$              | Isolation voltage                          | 50Hz, R.M.S., $t=1\text{min}, I_{ISO}=1\text{mA}(\text{MAX})$          |            | 3000  |      |      | V                              |
| $F_m$                  | Terminal connection torque (M8)            |  |            |       | 12.0 |      | N·m                            |
|                        | Mounting torque (M6)                       |  |            |       | 6.0  |      | N·m                            |
| $T_{vj}$               | Junction temperature                       |  |            | -40   |      | 125  | $^\circ\text{C}$               |
| $T_{stg}$              | Stored temperature                         |  |            | -40   |      | 125  | $^\circ\text{C}$               |
| $W_t$                  | Weight                                     |  |            |       | 810  |      | g                              |
| Outline                | 413F3D                                     |  |            |       |      |      |                                |

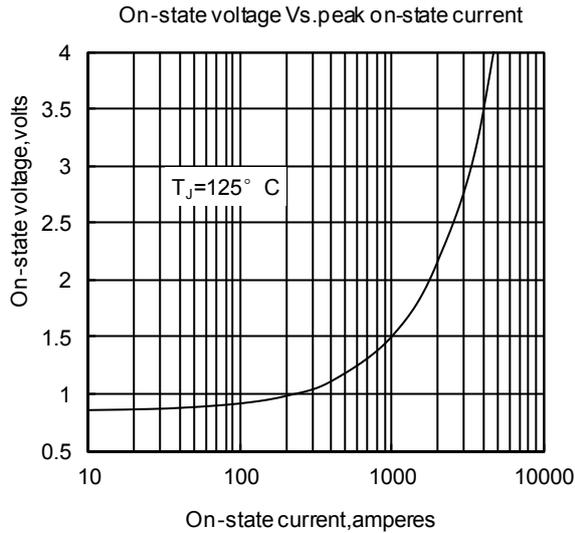


Fig. 1

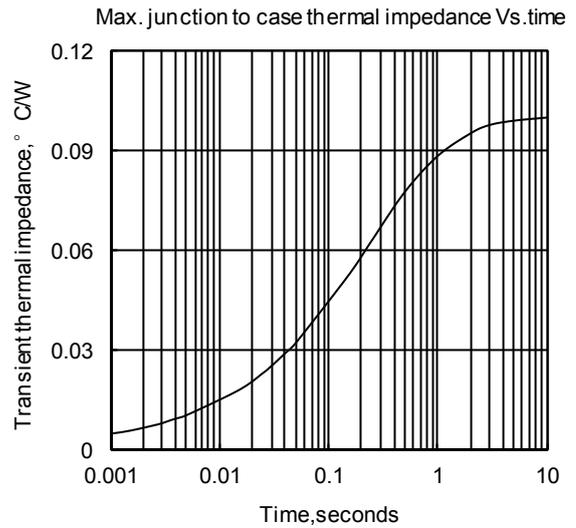


Fig. 2

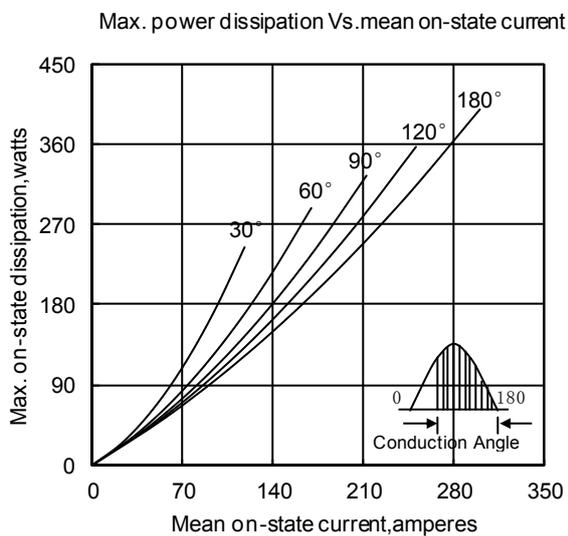


Fig. 3

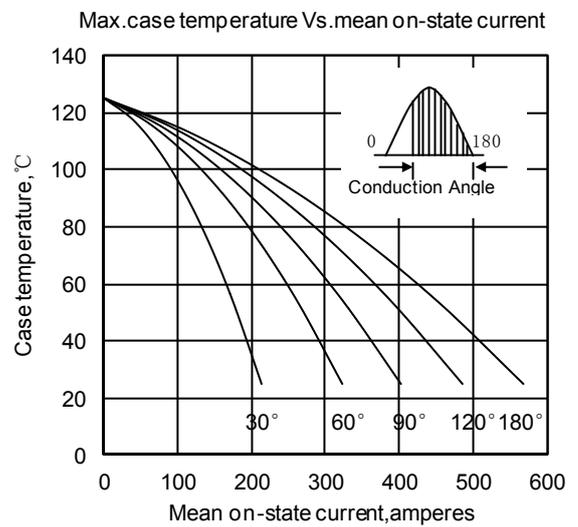


Fig. 4

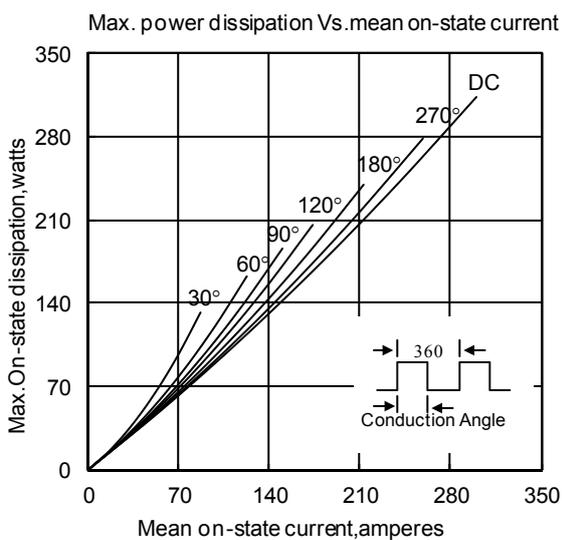


Fig. 5

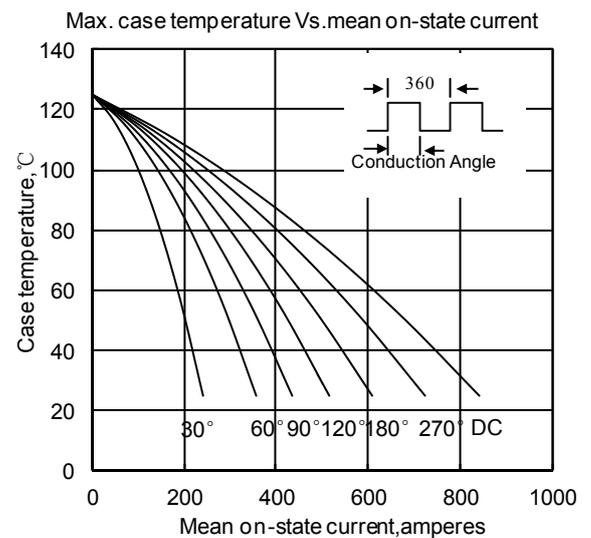


Fig. 6

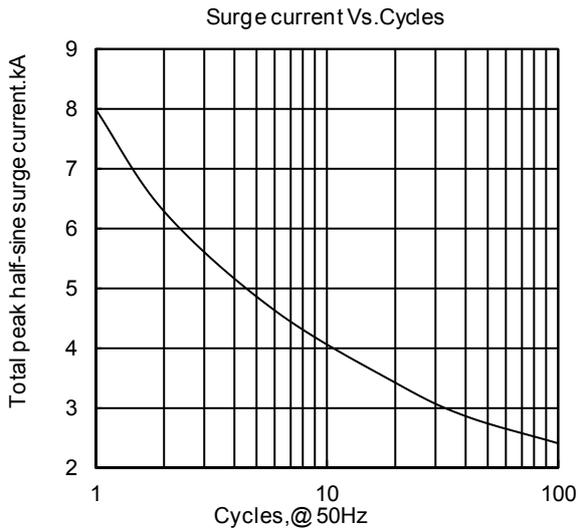


Fig. 7

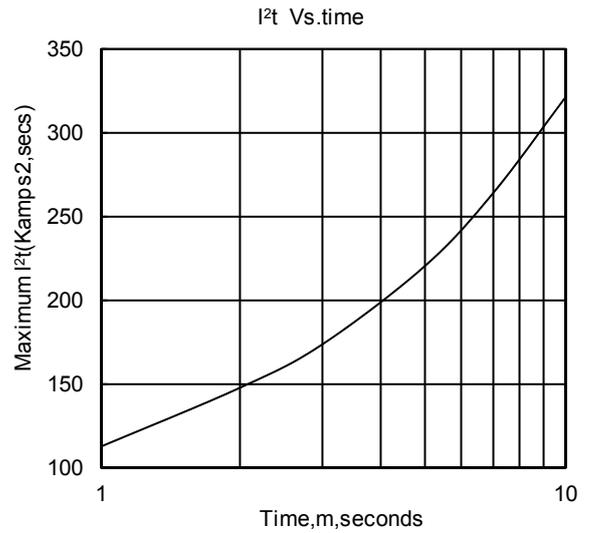


Fig. 8

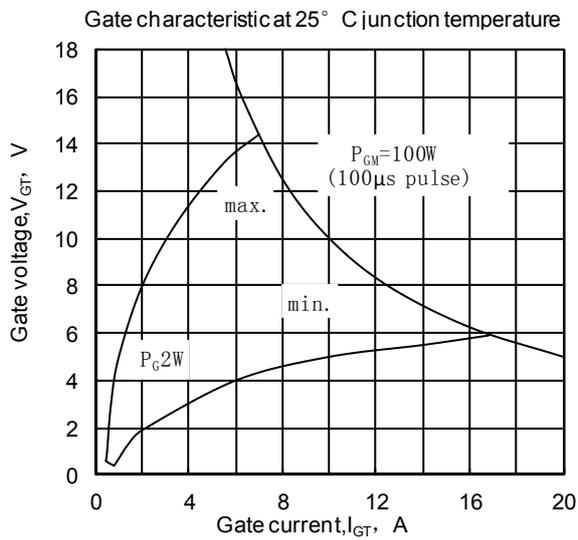


Fig. 9

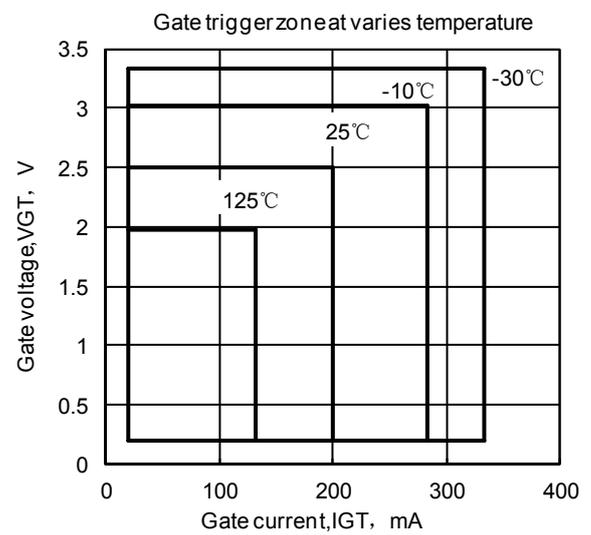


Fig. 10

Outline:

